## Lab #D -SDRAM

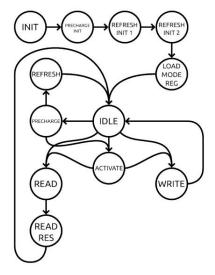
第九組

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### SDRAM controller design

#### SDRAM Controller

- INIT→IDLE
- IDLE→ACTIVATE→WRITE→IDLE
- IDLE→WRITE→IDLE
- IDLE→READ→READ RES→IDLE
- IDLE→PRECHARE→ACTIVATE→WRITE
   →IDLE
- IDLE→PRECHARE→ACTIVATE→READ
   →READ\_RES→IDLE
- IDLE→PRECHARE→REFRESH→IDLE



Reference: https://alchitry.com/sdram-mojo

**INIT**: The initial state where the SDRAM is initialized, and the internal logic control unit is initialized before normal SDRAM operation. In this lab, the process will proceed directly to the IDLE stage.

INIT --> IDLE

**IDLE**: Idle state, where after a bank is precharged, the SDRAM will be in the IDLE stage after a certain period.

ACTIVATE (row activate): When in the IDLE state, upon receiving a control signal, the bank and row are selected, transitioning to the ACTIVATE state.

IDLE --> ACTIVATE

different banks)

**WRITE:** In the row activate state, upon receiving a WRITE signal, the bank and column are selected, and the data writing process is executed.

IDLE --> ACTIVATE --> WRITE --> IDLE (Writing steps within the same bank)
IDLE --> PRECHARGE --> ACTIVATE --> WRITE --> IDLE (Writing steps involving

**READ :** In the row activate state, upon receiving a READ signal, the bank and column are selected, responsible for executing the SDRAM read steps.

IDLE --> ACTIVATE --> READ --> READ\_RES --> IDLE (Reading steps within the same bank)

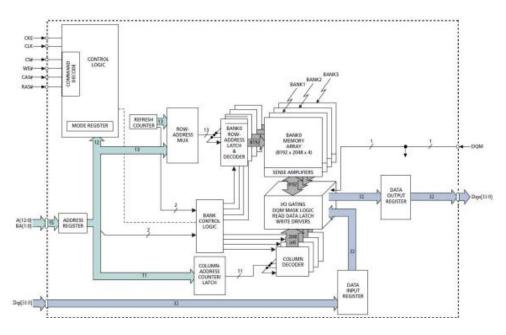
IDLE --> PRECHARGE --> ACTIVATE --> READ --> READ\_RES --> IDLE (Reading steps involving different banks)

**READ\_RES**: Reset performed after completing a read.

**PRECHARGE**: Precharging, necessary when closing a row. To perform read or write operations on a different bank, precharging is required to close the original bank and row.

**REFRESH**: To maintain the data in SDRAM, continuous refreshing is needed, mainly divided into two types: auto refresh and self-refresh. During auto refresh, all active banks need to undergo precharge before execution.

### **SDRAM** bus protocol



clk: Clock signal

Cke (sdram\_sle): Enable signal for the clk signal

Cas\_n (sdram\_cas): Column address strobe signal, input data for selecting the row

Ras\_n (sdram\_ras): Row address strobe signal, input data for selecting the column address.

We n (sdram we): Enable signal for write operations.

Dqm (sdram\_dqm): Data mask (Data I/O Mask), used to control which input or output data ports are disabled.

Ba (sdram ba): Bank address, primarily used to select which bank to use.

Addr (saram\_a): Address bus, depending on the current situation, it may be the address of the row or column.

Dqi (sdram\_dqi): Input for the original in-out pin.

Dqo (sdram\_dqo): Output for the original in-out pin.

### Introduce the prefetch scheme

```
always@(posedge clk)begin
    if(in_valid)
        prefetch_address <= addr + 22'd4;
else if(!in_valid && out_valid_q)
        prefetch_address <= 0;

if((prefetch_address == addr) && in_valid && !rw)
        prefetch <= 1;
else if((prefetch_address != addr) && in_valid & !rw)
        prefetch <= 0;
else if(rw)
        prefetch <= 0;
end</pre>
```

This is the condition setting for prefetching. Initially, when in\_valid equals 1, the prefetch\_address is incremented by 4. Next, it determines when prefetch should be set to 1, and this decision is made in the IDLE state.

During the implementation process, initially, we placed the prefetch bank access in the READ\_RES state and checked whether prefetching should be done in the IDLE state. Assuming prefetching is required, it would jump to the READ\_RES state to access the prefetch address. While this approach allowed prefetching, if the second read was from the same BANK, it still required a re-ACTIVATE. Consequently, we later added prefetch bank access even in the IDLE state. This means that if the second read is from the same bank, there is no need for a re-ACTIVATE.

In other words, during the first READ, an ACTIVATE is necessary, and this part requires a waiting time of 3 cycles. In the second instance, if the read is from the same BANK, only 3 cycles of READ are needed to retrieve the data. As a result, the time spent in READ\_RES is only 1 cycle, eliminating the need for the 3-cycle ACTIVATE waiting time.

#### Introduce the bank interleave for code and data

Separating Code and Data into different Banks facilitates the design of prefetching, providing clarity on which addresses store data to be loaded into the Processing Element (PE) for computation.

#### Bank Determination:

[1] The last 22 bits of the WB address are directly mapped to the SDRAM address.

Bank 0	3800_X 0 XX	3800_X 4 XX	3800_X 8 XX	3800_X C XX
Bank 1	3800_X 1 XX	3800_X 5 XX	3800_X 9 XX	3800_X D XX
Bank 2	3800_X 2 XX	3800_X 6 XX	3800_X A XX	3800_X E XX
Bank 3	3800_X 3 XX	3800_X 7 XX	3800_X B XX	3800_X F XX

Then, using wbs\_adr\_i[31:24], wbs\_stb\_i, and wbs\_cyc\_i to differentiate between req\_code (3800) and req\_data (3000). If request\_code is 1, it indicates the need to look at code\_adr and select the appropriate bank based on its data. The bank selection is either 2 (10) or 3 (11).

```
code_addr={wbs_adr_i[22:10], code_bank, wbs_adr_i[7:0]}
```

If req\_data is 1, it indicates the need to look at the data\_addr's address and choose which bank to use. The bank selection is either 0 (00) or 1 (01). data\_addr={wbs\_adr\_i[22:10], data\_bank, wbs\_adr\_i[7:0]}

```
wire req_data;
wire req_code;
wire[1:0] data_bank;//data
wire [22:0] data_addr;
wire[1:0] code_bank;//code
wire [22:0] code_addr;
assign req_data = (wbs_stb_i & wbs_cyc_i &(wbs_adr_i[31:24] == 8'h30)) ? 1 : 0;
assign req_code = (wbs_stb_i & wbs_cyc_i &(wbs_adr_i[31:24] == 8'h38)) ? 1 : 0;
assign data_bank = (wbs_adr_i[9:8]>2'b01) ? (wbs_adr_i[9:8]-2'b10) : wbs_adr_i[9:8];
assign data_addr = (req_data) ? {wbs_adr_i[2:10], data_bank, wbs_adr_i[7:0]} : 0;
assign code_bank = (wbs_adr_i[9:8]<2'b10) ? (wbs_adr_i[9:8]+2'b10) : wbs_adr_i[9:8];
assign code_addr = (req_code) ? {wbs_adr_i[22:10], code_bank, wbs_adr_i[7:0]} : 0;</pre>
```

# Introduce how to modify the linker to load address/data in two different bank

```
wire[1:0] data_bank;
assign data_bank = (wbs_adr_i[9:8]>2'b01) ? (wbs_adr_i[9:8]-2'b10) : wbs_adr_i[9:8];
wire [22:0] data_addr;
assign data_addr = (req_data) ? {wbs_adr_i[22:10], data_bank, wbs_adr_i[7:0]} : 0;
wire[1:0] code_bank;
assign code_bank = (wbs_adr_i[9:8]<2'b10) ? (wbs_adr_i[9:8]+2'b10) : wbs_adr_i[9:8];
wire [22:0] code_addr;
assign code_addr = (req_code) ? {wbs_adr_i[22:10], code_bank, wbs_adr_i[7:0]} : 0;</pre>
```

To set which bank to use within the user configuration, the following code is utilized. The decision is made based on the value of wbs\_adr\_i[9:8]. If wbs\_adr\_i[9:8] > 01, then data\_bank is determined as wbs\_adr\_i[9:8] - 2'b10 (00 or 01). If wbs\_adr\_i[9:8] < 10, then code\_bank is determined as wbs\_adr\_i[9:8] + 2'b10 (10 or 11).

# Observe SDRAM access conflicts with SDRAM refresh (reduce the refresh period)

The reliability of data in SDRAM is ensured through the use of the refresh technique, which involves periodic refreshing operations. However, conflicts may arise when system accesses and refresh operations occur simultaneously on the same section. To mitigate such situations, it is advisable to reduce the refresh cycle, minimizing the chances of conflicts.